



13-BIT TO 26-BIT REGISTERED *IDT74SSTVM16859* BUFFER WITH SSTL I/O ADVANCE INFORMATION

FEATURES:

- 1:2 register buffer
- Meets or exceeds JEDEC standard SSTVM16859
- 2.3V to 2.7V Operation
- SSTL_2 Class II style data inputs/outputs
- Differential CLK input
- $\overline{\text{RESET}}$ control compatible with LVC MOS levels
- Latch-up performance exceeds 100mA
- ESD >2000V per MIL-STD-883, Method 3015; >200V using machine model (C = 200pF, R = 0)
- Available in 56 pin MLF and 64 pin TSSOP packages

APPLICATIONS:

- Along with CSPT857C, Zero Delay PLL Clock buffer, provides complete solution for DDR1 registered DIMMs

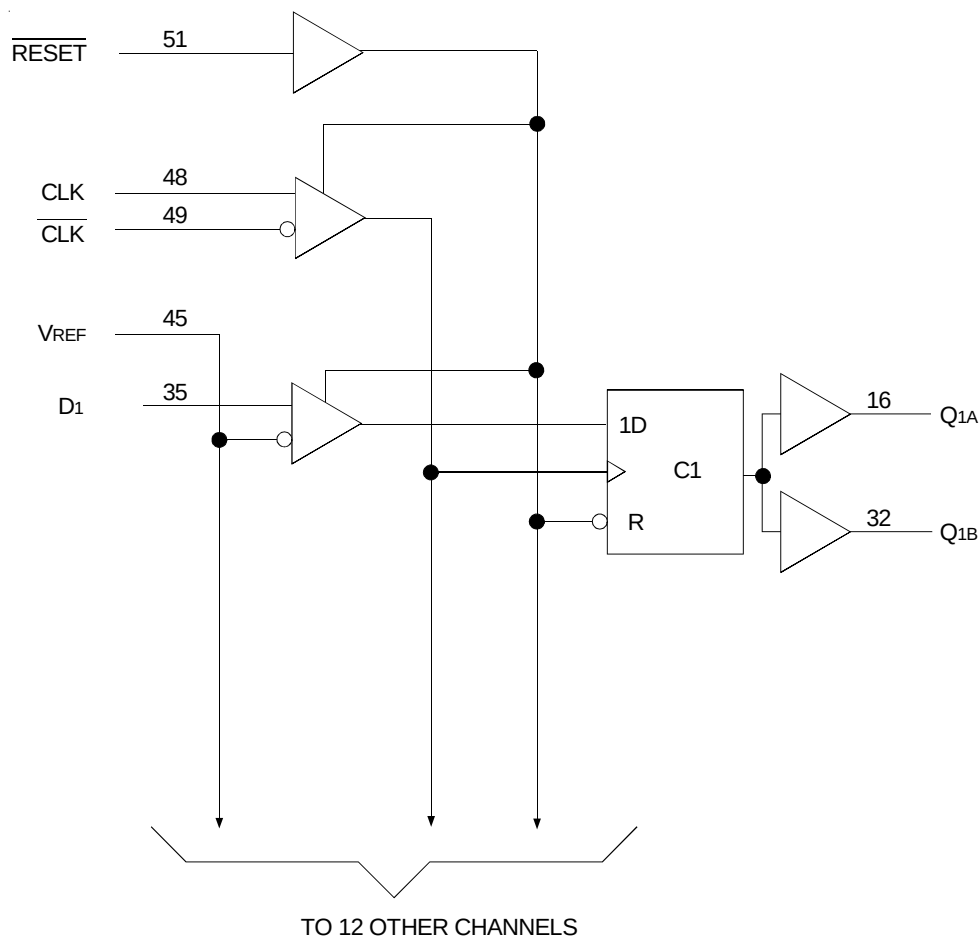
DESCRIPTION:

The SSTVM16859 is a 13-bit to 26-bit registered buffer designed for 2.3V-2.7V V_{DD} and supports low standby operation. All data inputs and outputs are SSTL_2 level compatible with JEDEC standard for SSTL_2.

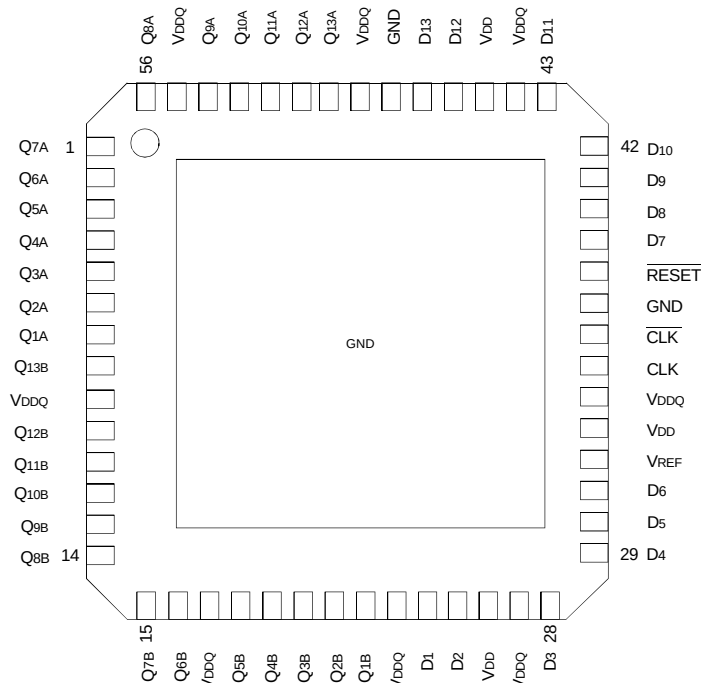
$\overline{\text{RESET}}$ is an LVC MOS input since it must operate predictably during the power-up phase. $\overline{\text{RESET}}$, which can be operated independent of CLK and $\overline{\text{CLK}}$, must be held in the low state during power-up in order to ensure predictable outputs (low state) before a stable clock has been applied.

$\overline{\text{RESET}}$, when in the low state, will disable all input receivers, reset all registers, and force all outputs to a low state, before a stable clock has been applied. With inputs held low and a stable clock applied, outputs will remain low during the Low-to-High transition of $\overline{\text{RESET}}$.

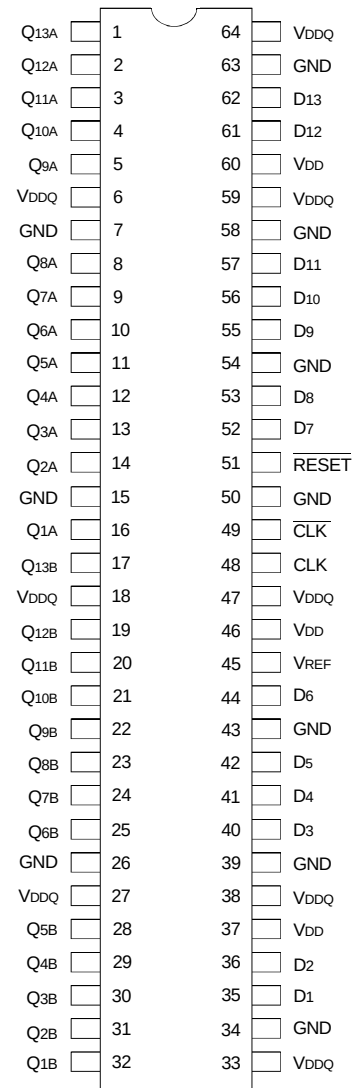
FUNCTIONAL BLOCK DIAGRAM



PIN CONFIGURATIONS



**MLF
TOP VIEW**



**TSSOP
TOP VIEW**

ABSOLUTE MAXIMUM RATINGS (1)

Symbol	Description	Max.	Unit
V _{DD} or V _{DDQ}	Supply Voltage Range	-0.5 to 3.6	V
V _I ⁽²⁾	Input Voltage Range	-0.5 to V _{DD} + 0.5	V
V _O ⁽³⁾	Output Voltage Range	-0.5 to V _{DDQ} + 0.5	V
I _{IK}	Input Clamp Current, V _I < 0	-50	mA
I _{OK}	Output Clamp Current, V _O < 0 or V _O > V _{DDQ}	±50	mA
I _O	Continuous Output Current, V _O = 0 to V _{DDQ}	±50	mA
V _{DD}	Continuous Current through each V _{DD} , V _{DDQ} or GND	±100	mA
T _{STG}	Storage Temperature Range	-65 to +150	°C

NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- The input and output negative voltage ratings may be exceeded if the ratings of the I/P and O/P clamp current are observed.
- The output current will flow if the following conditions are observed:
 - Output in HIGH state
 - V_O = V_{DDQ}

FUNCTION TABLE (1)

Input				Q Outputs
$\overline{\text{RESET}}$	CLK	$\overline{\text{CLK}}$	D	
H	↑	↓	L	L
H	↑	↓	H	H
H	L or H	L or H	X	Q ₀ ⁽²⁾
L	X	X	X	L

NOTES:

- H = HIGH Voltage Level
 L = LOW Voltage Level
 X = Don't Care
 ↑ = LOW to HIGH
 ↓ = HIGH to LOW
- Q₀ = Output level before the indicated steady-state conditions were established.

PIN DESCRIPTION

Pin Names	Description
Q1 - Q13	Data Output
GND	Ground
V _{DDQ}	Output-stage drain power voltage
V _{DD}	Logic power voltage
$\overline{\text{RESET}}$	Asynchronous reset input - resets registers and disables data and clock differential input receivers
V _{REF}	Input reference voltage
CLK	Positive master clock input
$\overline{\text{CLK}}$	Negative master clock input
D1 - D13	Data Input - clocked in on the crossing of the rising edge of CLK and the falling edge of $\overline{\text{CLK}}$
Center PAD	Ground (MLF package only)

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: T_A = 0°C to +70°C, V_{DD} = 2.5V ±0.2V, V_{DDQ} = 2.5V ±0.2V

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V _{IK}	Control Inputs	V _{DD} = 2.3V, I _I = -18mA	—	—	-1.2	V
V _{OH}		V _{DD} = 2.3V to 2.7V, I _{OH} = -100μA	V _{DD} - 0.2	—	—	V
		V _{DD} = 2.3V, I _{OH} = -16mA	1.95	—	—	
V _{OL}		V _{DD} = 2.3V to 2.7V, I _{OL} = 100μA	—	—	0.2	V
		V _{DD} = 2.3V, I _{OL} = 16mA	—	—	0.35	
I _I	All Inputs	V _{DD} = 2.7V, V _I = V _{DD} or GND	—	—	±5	μA
I _{DD}	Static Standby	I _O = 0, V _{DD} = 2.7V, $\overline{\text{RESET}}$ = GND	—	—	0.01	mA
	Static Operating	I _O = 0, V _{DD} = 2.7V, $\overline{\text{RESET}}$ = V _{DD} , V _I = V _{IH} (AC) or V _{IL} (AC)	—	—	20	
I _{DDQ}	Dynamic Operating (Clock Only)	I _O = 0, V _{DD} = 2.7V, $\overline{\text{RESET}}$ = V _{DD} , V _I = V _{IH} (AC) or V _{IL} (AC), CLK and $\overline{\text{CLK}}$ Switching 50% Duty Cycle.	—	6	—	μA/Clock MHz
	Dynamic Operating (Per Each Data Input) ⁽¹⁾	I _O = 0, V _{DD} = 2.7V, $\overline{\text{RESET}}$ = V _{DD} , V _I = V _{IH} (AC) or V _{IL} (AC), CLK and $\overline{\text{CLK}}$ Switching 50% Duty Cycle. One Data Input Switching at Half Clock Frequency, 50% Duty Cycle.	—	43	—	μA/Clock MHz/Data Input
r _{OH}	Output HIGH	V _{DD} = 2.3V to 2.7V, I _{OH} = -20mA	7	—	20	Ω
r _{OL}	Output LOW	V _{DD} = 2.3V to 2.7V, I _{OH} = 20mA	7	—	20	Ω
r _{O(A)}	r _{OH} - r _{OL} each separate bit	V _{DD} = 2.5V, T _A = 25°C, I _{OH} = -20mA	—	—	4	Ω
C _I	Data Inputs	V _{DD} = 2.5V, V _I = V _{REF} ± 310mV	2	—	3	pF
	CLK and $\overline{\text{CLK}}$	V _{ICR} = 1.25V, V _I (PP) = 360mV	2	—	3	
	$\overline{\text{RESET}}$	V _I = V _{DD} or GND	2	—	3	

NOTE:

- Power dissipation levels will allow operation at DDR333 speeds without excessive die temperature.

OPERATING CHARACTERISTICS, $T_A = 25^\circ\text{C}$ (1)

Symbol	Parameter	Min.	Typ. ⁽¹⁾	Max.	Unit
V _{DD}	Supply Voltage	V _{DDQ}	—	2.7	V
V _{DDQ}	Output Supply Voltage	2.3	2.5	2.7	V
V _{REF}	Reference Voltage (V _{REF} = V _{DDQ} /2)	1.15	1.25	1.35	V
V _{TT}	Termination Voltage	V _{REF} – 40mV	V _{REF}	V _{REF} + 40mV	V
V _I	Input Voltage	0	—	V _{DD}	V
V _{IH}	AC High-Level Input Voltage	Data Inputs	V _{REF} + 310mV	—	V
V _{IL}	AC Low-Level Input Voltage	Data Inputs	—	V _{REF} – 310mV	V
V _{IH}	DC High-Level Input Voltage	Data Inputs	V _{REF} + 150mV	—	V
V _{IL}	DC Low-Level Input Voltage	Data Inputs	—	V _{REF} – 150mV	V
V _{IH}	High-Level Input Voltage	$\overline{\text{RESET}}$	1.7	—	V
V _{IL}	Low-Level Input Voltage	$\overline{\text{RESET}}$	—	0.7	V
V _{ICR}	Common-Mode Input Range	CLK, $\overline{\text{CLK}}$	0.97	1.53	V
V _{I(PP)}	Peak-to-Peak Input Voltage	CLK, $\overline{\text{CLK}}$	360	—	mV
I _{OH}	High-Level Output Current	—	—	–20	mA
I _{OL}	Low-Level Output Current	—	—	20	
T _A	Operating Free-Air Temperature	0	—	+70	°C

NOTE:

1. The $\overline{\text{RESET}}$ input of the device must be held at V_{DD} or GND to ensure proper device operation.

TIMING REQUIREMENTS OVER RECOMMENDED OPERATING FREE-AIR TEMPERATURE RANGE

Symbol	Parameter	V _{DD} = 2.5V ± 0.2V		Unit
		Min.	Max.	
CLOCK	Clock Frequency	—	200	MHz
t _W	Pulse Duration, CLK, $\overline{\text{CLK}}$ HIGH or LOW	2.5	—	ns
t _{ACT}	Differential Inputs Active Time ⁽¹⁾	—	22	ns
t _{INACT}	Differential Inputs Inactive Time ⁽²⁾	—	22	ns
t _{SU}	Setup Time, Fast Slew Rate ^(3,5)	Data Before CLK↑, CLK↓	0.65	ns
	Setup Time, Slow Slew Rate ^(4,5)		0.75	ns
t _H	Hold Time, Fast Slew Rate ^(3,5)	Data Before CLK↑, CLK↓	0.75	ns
	Hold Time, Slow Slew Rate ^(2,5)		0.9	ns

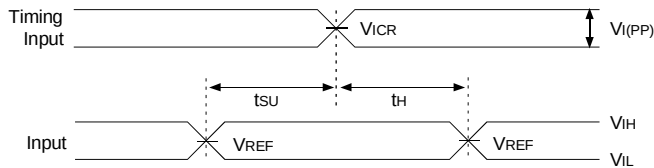
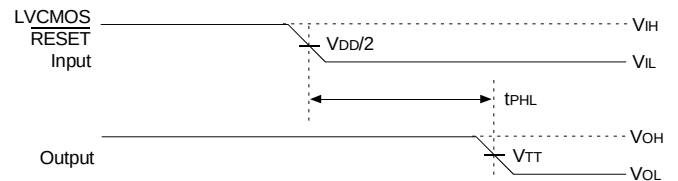
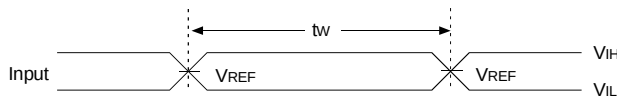
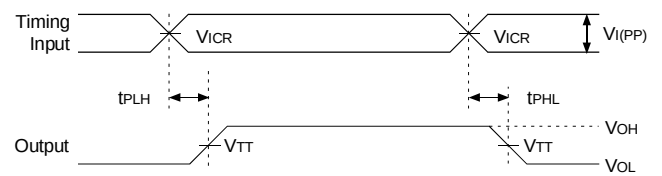
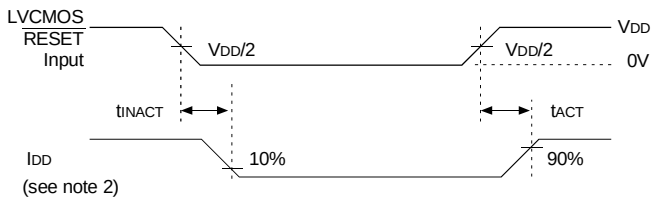
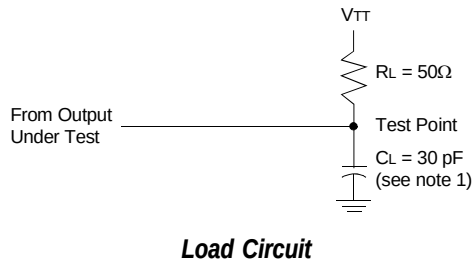
NOTES:

1. Data inputs must be low a minimum time of t_{ACT} max., after $\overline{\text{RESET}}$ is taken HIGH.
2. Data and clock inputs must be held at valid levels (not floating) a minimum time of t_{INACT} max., after $\overline{\text{RESET}}$ is taken LOW.
3. For data signal input slew rate is ≥1V/ns.
4. For data signal input slew rate is ≥0.5V/ns and <1V/ns.
5. CLK, $\overline{\text{CLK}}$ signal input slew rates are ≥1V/ns.

SWITCHING CHARACTERISTICS OVER RECOMMENDED FREE-AIR OPERATING RANGE (UNLESS OTHERWISE NOTED)

Symbol	Parameter	V _{DD} = 2.5V ± 0.2V		Unit
		Min.	Max.	
f _{MAX}		200	—	MHz
t _{PDM}	CLK and $\overline{\text{CLK}}$ to Q	1.1	2.6	ns
t _{PDMS}	CLK and $\overline{\text{CLK}}$ to Q (simultaneous switching)	—	2.9	ns
t _{PHL}	$\overline{\text{RESET}}$ to Q	—	5	ns

TEST CIRCUITS AND WAVEFORMS ($V_{DD} = 2.5V \pm 0.2V$)



NOTES:

1. C_L includes probe and jig capacitance.
2. I_{DD} tested with clock and data inputs held at V_{DD} or GND, and $I_O = 0mA$.
3. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10MHz$, $Z_o = 50\Omega$, input slew rate = $1 V/ns \pm 20\%$ (unless otherwise specified).
4. The outputs are measured one at a time with one transition per measurement.
5. $V_{TT} = V_{REF} = V_{DDQ}/2$
6. $V_{IH} = V_{REF} + 310mV$ (AC voltage levels) for differential inputs. $V_{IH} = V_{DD}$ for LVC MOS input.
7. $V_{IL} = V_{REF} - 310mV$ (AC voltage levels) for differential inputs. $V_{IL} = GND$ for LVC MOS input.
8. t_{PDM} is t_{PD} with one output switching. t_{PDMSS} is t_{PD} with all outputs switching.

ORDERING INFORMATION

IDT74SSTVM	XX	XXX	XX	XX	
	Family	Device Type	Package	Process	
				Blank	0°C to +70°C (Commercial)
				PA	Thin Shrink Small Outline Package
				NL	Thermally Enhanced Plastic Very Fine Pitch Quad Flat No Lead Package
				859	13-Bit to 26-Bit Registered Buffer with SSTL I/O
				16	Double-Density



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